

HW #4

Due October 23 (Tuesday) in class

1. In this problem, you will calculate and plot the band diagram of an P-Al_{0.4}Ga_{0.6}As / i-GaAs / N-Al_{0.4}Ga_{0.6}As double heterojunction with $N_a = 3 \times 10^{17} \text{ cm}^{-3}$ and $N_d = 3 \times 10^{17} \text{ cm}^{-3}$. The GaAs is intrinsic. The thickness of the GaAs layer is 0.1 μm . Use the material properties listed in the Table below.

	Unit	GaAs	Al _x Ga _{1-x} As, 0 < x < 0.45
Bandgap Energy	eV	1.424	1.424 + 1.247x
Electron Effective Mass	m ₀	0.067	0.067 + 0.083x
Hole Effective Mass	m ₀	0.5	0.5 + 0.29x
Dielectric Constant	ε ₀	13.1	13.1 – 3x
Conduction Band Discontinuity	%	-	ΔE _c ~ 67% ΔE _g
Valence Band Discontinuity	%	-	ΔE _v ~ 33% ΔE _g

The conduction and valence band density of states are

$$N_c = 2 \left(\frac{\pi m_e^* k_B T}{2\pi^2 \hbar^2} \right)^{3/2} = 2.5 \times 10^{19} \left(\frac{m_e^*}{m_0} \cdot \frac{T}{300} \right)^{3/2}$$

$$N_v = 2 \left(\frac{\pi m_h^* k_B T}{2\pi^2 \hbar^2} \right)^{3/2} = 2.5 \times 10^{19} \left(\frac{m_h^*}{m_0} \cdot \frac{T}{300} \right)^{3/2}$$

- Calculate Fermi energy in each individual semiconductor. Find the contact potential (built-in potential), V_0 .
 - Assume the depletion region on the P and the N sides are $-0.5 \mu\text{m} - x_P$ and $0.5 \mu\text{m} + x_N$, respectively. We will solve for x_P and x_N later. Plot the charge distribution $\rho(x)$. What is the relation between x_P and x_N ? (*Hint: there is no charge in the i-region*).
 - Calculate and plot the electric field distribution $E(x)$. Show the analytical expression. (*Hint: the electric field in the i-region should be constant*).
 - Calculate and plot the electron potential energy distribution, $-q\phi(x)$. Show the analytical expression. (*Hint: the electron potential energy varies linearly in the i-region*).
 - Equate the electron potential difference between the N- and the P-AlGaAs to the contact potential, V_0 , solve for x_P and x_N .
 - Now plot the entire band diagram quantitatively.
2. Repeat Problem 1 for a forward bias voltage of 0.7V. You don't need to show all the detailed steps, just those you need to derive the final band diagram. Show the quasi-Fermi levels.
3. Plot the electron and hole concentration distribution across the double heterojunction under the condition of Problem 2. Use logarithmic scale for the vertical axis as the concentration varies over a very large range when going from majority to minority side.